

# AMP1139 SOLID STATE HIGH POWER AMPLIFIER

## FEATURES

- Class AB linear GaN design
- Instantaneous ultra-wide bandwidth
- Suitable for all single channel modulations standards
- Built-in protection circuits
- High reliability and ruggedness



## ELECTRICAL SPECIFICATIONS

Parameter	Specification	Notes
Operating Frequency Range	9KHz - 1.0 GHz	
Power Output Psat	2 Watt Min	CW
Power Gain	33 dB Min	
Gain Flatness	4.0 dB p-p Max	
Input Return Loss	10 dB Min	Relative to 50 Ohm
Harmonics 2 <sup>nd</sup> / 3rd	>15 dBc / >20 dBc Typ	At rated Pout
2-Tone Intermodulation (IMD)	>30 dBc Typ	23dBm/Tone, Δ = 1MHz
Non Harmonics Spurious	>60 dBc	
Operating Voltage	28 VDC Nom	
Current Consumption	1 Amp Max	At rated Pout
Max Input Power	+8 dBm	Without damage
Load VSWR Protection	∞ : 1	

## ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Case Temperature	-20 to +75 °C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	Non Condensation

## MECHANICAL SPECIFICATIONS

Parameter	Specification	Notes
Dimensions	100 x 80 x 27 mm	
Weight	300 gr.	Typical Weight
RF Connectors In/Out	SMA female	
DC Power / Interface Connector	9-Pin D-Sub	
Cooling	External Heatsink	Forced air required

## D-SUB CONNECTOR PIN ASSIGNMENT

Pin	Function	Description
1	FWD	N/C
2	REV	N/C
3	CURRENT SENSOR	I <sub>b</sub> @20mV/100mA Typ
4	TEMP SENSOR	V <sub>T</sub> @10mV/°C + 500mV Typ
5	SHUTDOWN	TTL
6, 7	VDD	28VDC
8, 9	GND	Ground



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**OUTLINE DRAWING**